



HIGH-SPEED CMOS BUS INTERFACE 10-BIT LATCH

IDTQS74FCT2841AT/BT/CT

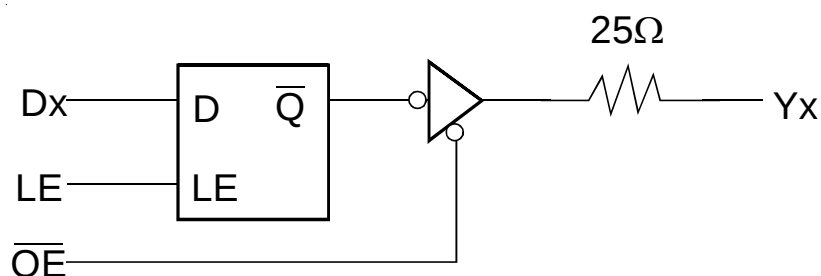
FEATURES:

- CMOS power levels: <7.5mW static
- Undershoot clamp diodes on all outputs
- True TTL input and output compatibility
- Ground bounce controlled outputs
- Reduced output swing of 0 to 3.5V
- Built-in 25Ω series resistor outputs reduce reflection and other system noise
- A, B, and C speed grades with 5.5ns t_{PD} for C
- $I_{OL} = 12mA$
- Available in SOIC and QSOP packages

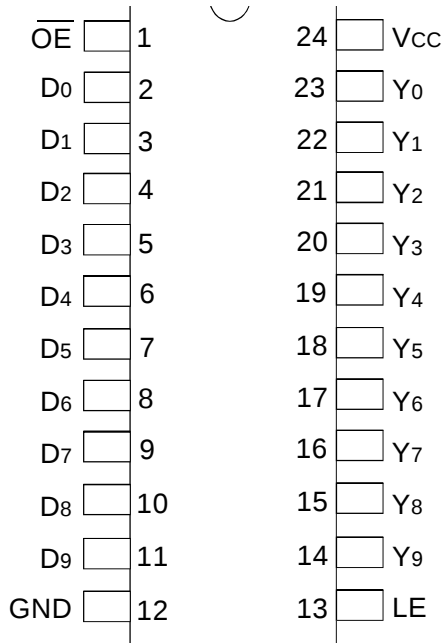
DESCRIPTION:

The IDTQS74FCT2841T is a 10-bit high-speed CMOS TTL-compatible buffered latch with 3-state outputs, with a 25Ω resistor that is useful for driving transmission lines and reducing system noise. The 2841 eliminates the need for external series resistors in high speed systems and can replace the 841 series to reduce noise in an existing design. All inputs have clamp diodes for undershoot noise suppression. All outputs have ground bounce suppression. Outputs will not load an active bus when Vcc is removed from the device.

FUNCTIONAL BLOCK DIAGRAM



PIN CONFIGURATION

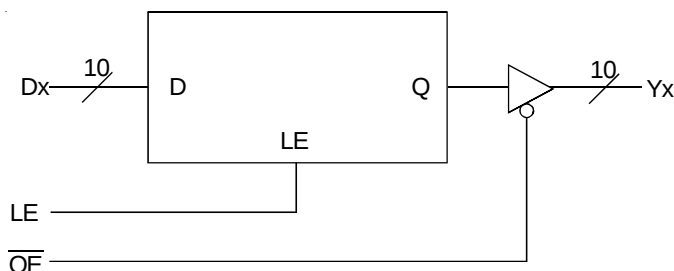


SOIC/ QSOP
TOP VIEW

PIN DESCRIPTION

Pin Names	I/O	Description
Dx	I	Latch Data Inputs
LE	I	The latch enable input. The latches are transparent when LE is HIGH. Input data is latched on the HIGH-to-LOW transition.
Yx	O	3-State Latch Outputs
$\overline{OE}$	I	The output enable control. When $\overline{OE}$ is LOW, the outputs are enabled. When $\overline{OE}$ is HIGH, the outputs Yx are in high-impedance (off) state.

LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM	Terminal Voltage with Respect to GND	-0.5 to +7	V
TSTG	Storage Temperature	-65 to +150	°C
IOUT	DC Output Current Max Sink Current/Pin	120	mA
I _{IK}	Input Diode Current, V _{IN} < 0	-20	mA
I _{OK}	Output Diode Current, V _{OUT} < 0	-50	mA

NOTE:

- Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

CAPACITANCE (T_A = +25°C, F = 1.0MHz)

Symbol	Parameter ⁽¹⁾	Conditions	Typ.	Max.	Unit
C _{IN} ⁽²⁾	Input Capacitance	V _{IN} = 0V	4	—	pF
C _{OUT} ⁽³⁾	Output Capacitance	V _{OUT} = 0V	6	—	pF
C _{OUT} ⁽⁴⁾	Output Capacitance	V _{OUT} = 0V	4	—	pF

NOTES:

- This parameter is measured at characterization but not tested.
- Pins 1-11, 13.
- Pins 15-22.
- Pins 14, 23.

FUNCTION TABLE⁽¹⁾

Inputs			Internal Value Qx	Outputs Yx	Function
$\overline{OE}$	LE	Dx			
H	H	L	L	Z	High-Z
H	H	H	H	Z	High-Z
H	L	X	NC	Z	Latched (High-Z)
L	H	L	L	L	Transparent
L	H	H	H	H	Transparent
L	L	X	NC	NC	Latched

NOTE:

- H = HIGH Voltage Level
L = LOW Voltage Level
X = Don't Care
NC = No Change
Z = High-Impedance

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified:

Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions		Min.	Typ. ⁽¹⁾	Max.	Unit
V_{IH}	Input HIGH Level	Guaranteed Logic HIGH Level		2	—	—	V
V_{IL}	Input LOW Level	Guaranteed Logic LOW Level		—	—	0.8	V
ΔV_T	Input Hysteresis	$V_{TLH} - V_{THL}$ for all inputs		—	0.2	—	V
I_{IH}	Input HIGH Current	$V_{CC} = \text{Max.}$	$0 \leq V_{IN} \leq V_{CC}$	—	—	± 5	μA
I_{IL}	Input LOW Current						
I_{OZ}	Off-State Output Current (Hi-Z)	$V_{CC} = \text{Max.}$	$0 \leq V_{IN} \leq V_{CC}$	—	—	± 5	μA
I_{OR}	Current Drive	$V_{CC} = \text{Max.}$, $V_{OUT} = 2.0\text{V}^{(2)}$		50	—	—	mA
V_{IC}	Input Clamp Voltage	$V_{CC} = \text{Min.}$, $I_{IN} = -18\text{mA}$, $T_A = 25^{\circ}\text{C}^{(2)}$		—	-0.7	-1.2	V
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min.}$	$I_{OH} = -15\text{mA}$	2.4	—	—	V
V_{OL}	Output LOW Voltage	$V_{CC} = \text{Min.}$	$I_{OL} = 12\text{mA}$	—	—	0.5	V
$R_{OUT}^{(3)}$	Output Resistance	$V_{CC} = \text{Min.}$	$I_{OH} = 12\text{mA}$	18	25	40	Ω

NOTES:

- Typical values are at $V_{CC} = 5.0\text{V}$, $T_A = 25^{\circ}\text{C}$.
- This parameter is measured at characterization but not tested.
- R_{OUT} changed on March 8, 2002. See rear page for more information.

POWER SUPPLY CHARACTERISTICS

Following Conditions Apply Unless Otherwise Specified:

Industrial: $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$, $V_{CC} = 5.0\text{V} \pm 5\%$

Symbol	Parameter	Test Conditions ⁽¹⁾	Min.	Max.	Unit
I_{CC}	Quiescent Power Supply Current	$V_{CC} = \text{Max.}$ freq = 0 $0\text{V} \leq V_{IN} \leq 0.2\text{V}$ or $V_{CC} - 0.2\text{V} \leq V_{IN} \leq V_{CC}$	—	1.5	mA
ΔI_{CC}	Supply Current per Input TTL Inputs HIGH	$V_{CC} = \text{Max.}$ $V_{IN} = 3.4\text{V}^{(2)}$ freq = 0	—	2	mA
I_{CCD}	Supply Current per Input per MHz	$V_{CC} = \text{Max.}$ Outputs Open and Enabled One Bit Toggling 50% Duty Cycle Other inputs at GND or $V_{CC}^{(3,4)}$	—	0.25	mA/MHz

NOTES:

- For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.
- Per TLL driven input ($V_{IN} = 3.4\text{V}$).
- For flip-flops, I_{CCD} is measured by switching one of the data input pins so that the output changes every clock cycle. This is a measurement of device power consumption only and does not include power to drive load capacitance or tester capacitance.
- $I_C = I_{QUIESCENT} + I_{INPUTS} + I_{DYNAMIC}$
 $I_C = I_{CC} + \Delta I_{CC} D_H N_T + I_{CCD} (f_{CP}/2 + f_i N_i)$
 $I_{CC} = \text{Quiescent Current}$
 $\Delta I_{CC} = \text{Power Supply Current for a TTL High Input } (V_{IN} = 3.4\text{V})$
 $D_H = \text{Duty Cycle for TTL Inputs High}$
 $N_T = \text{Number of TTL Inputs at } D_H$
 $I_{CCD} = \text{Dynamic Current Caused by an Output Transition Pair (HLH or LHL)}$
 $f_{CP} = \text{Clock Frequency for Register Devices (Zero for Non-Register Devices)}$
 $f_i = \text{Input Frequency}$
 $N_i = \text{Number of Inputs at } f_i$
 All currents are in milliamps and all frequencies are in megahertz.

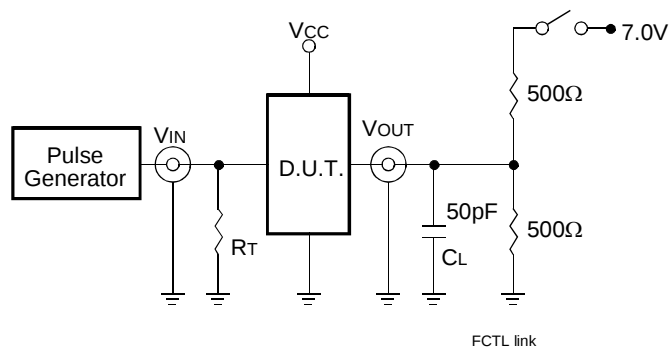
SWITCHING CHARACTERISTICS OVER OPERATING RANGE⁽¹⁾

Symbol	Parameter ⁽²⁾	FCT2841AT		FCT2841BT		FCT2841CT		Unit
		Min.	Max.	Min.	Max.	Min.	Max.	
t _{PLH} t _{PHL}	Data to Y Delay $\overline{OE} = \text{LOW}$	—	9.5	—	6.5	—	5.5	ns
t _{PLH} t _{PHL}	Data to Y Delay ^(3,4) $\overline{OE} = \text{LOW}$	—	20	—	13	—	13	ns
t _{SU}	Data to LE Setup Time	2.5	—	2.5	—	2.5	—	ns
t _H	Data to LE Hold Time	2.5	—	2.5	—	2.5	—	ns
t _{LEY}	LE to Y Delay $\overline{OE} = \text{LOW}$	—	12	—	8	—	8	ns
t _{LEY}	LE to Y Delay ^(3,4) $\overline{OE} = \text{LOW}$	—	16	—	15.5	—	15	ns
t _W	LE Pulse Width, HIGH ⁽³⁾	6	—	4	—	4	—	ns
t _{PZH} t _{PZL}	Output Enable Time $\overline{OE}$ to Yx	—	11.5	—	8	—	6.5	ns
t _{PZH} t _{PZL}	Output Enable Time ^(3,4) $\overline{OE}$ to Yx	—	23	—	14	—	12	ns
t _{PHZ} t _{PLZ}	Output Disable Time ^(3,5) $\overline{OE}$ to Yx	—	7	—	6	—	5.7	ns
t _{PHZ} t _{PLZ}	Output Disable Time ⁽³⁾ $\overline{OE}$ to Yx	—	8	—	7	—	6	ns

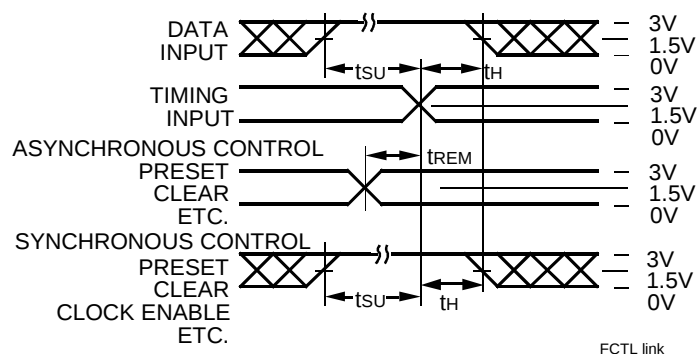
NOTES:

1. C_{LOAD} = 50pF, R_{LOAD} = 500Ω unless otherwise noted.
2. See Test Circuits and Waveforms
3. This parameter is guaranteed by design but not tested.
4. C_{LOAD} = 300pF.
5. C_{LOAD} = 5pF.

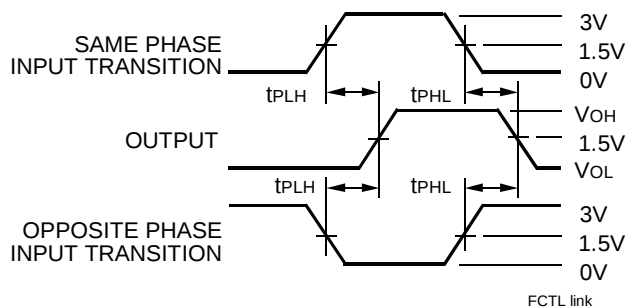
TEST CIRCUITS AND WAVEFORMS



Test Circuits for All Outputs



Set-Up, Hold, and Release Times



Propagation Delay

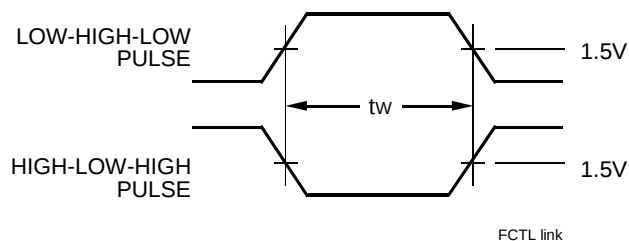
SWITCH POSITION

Test	Switch
Open Drain Disable Low Enable Low	Closed
All Other Tests	Open

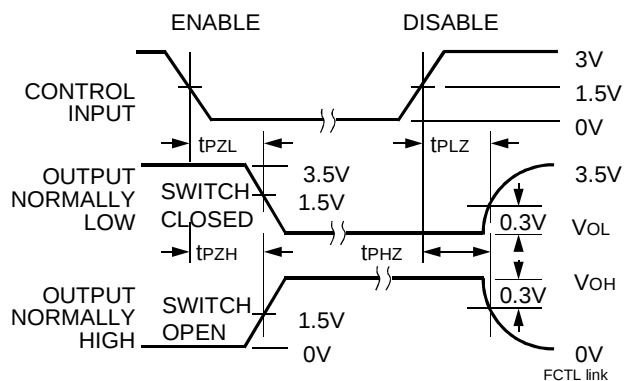
DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.



Pulse Width



Enable and Disable Times

NOTES:

- Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.
- Pulse Generator for All Pulses: Rate $\leq 1.0\text{MHz}$; $t_r \leq 2.5\text{ns}$; $t_f \leq 2.5\text{ns}$.

ORDERING INFORMATION

IDTQS	XX	FCT	XXXX	XX	
	Temp. Range		Device Type	Package	
				SO	Small Outline IC (gull wing)
				Q	Quarter Size Small Outline Package
			2841AT		High-Speed CMOS Bus Interface 10-Bit Latch
			2841BT		
			2841CT		
				74	−40°C to +85°C

As per PCN L0201-02, the Output Resistance (R_{OUT}) specifications have changed as of March 8, 2002. The original specifications were:

Parameter	Description	Min.	Typ.	Max.	Unit
R_{OUT}	$V_{CC} = \text{Min}, I_{OL} = -15\text{mA}$	20	28	40	Ω



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